INTEGRATED CIRCUITS



Product specification IC23 Data Handbook 1993 Jun 21



Philips Semiconductors

Octal transceiver with dual enable, inverting (3-State)

74ABT620

FEATURES

- Octal bidirectional bus interface
- 3-State buffers
- Power-up 3-State
- Live insertion/extraction permitted
- Output capability: +64mA/–32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

DESCRIPTION

The 74ABT620 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT620 device is an octal transceiver featuring inverting 3-State bus compatible outputs in both send and receive directions. The 74ABT620 is designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timing. This device allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic levels at the Enable inputs (OEBA and OEAB). The Enable inputs can be used to disable the device so that the buses are effectively isolated.

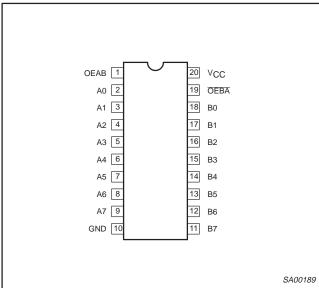
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	C _L = 50pF; V _{CC} = 5V	3.1	ns
C _{IN}	Input capacitance OEAB, OEBA	$V_{I} = 0V \text{ or } V_{CC}$	4	pF
C _{I/O}	I/O capacitance	Outputs disabled; $V_O = 0V$ or V_{CC}	7	pF
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} = 5.5V	50	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic DIP	–40°C to +85°C	74ABT620 N	74ABT620 N	SOT146-1
20-Pin plastic SO	–40°C to +85°C	74ABT620 D	74ABT620 D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +85°C	74ABT620 DB	74ABT620 DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40°C to +85°C	74ABT620 PW	74ABT620PW DH	SOT360-1

PIN CONFIGURATION



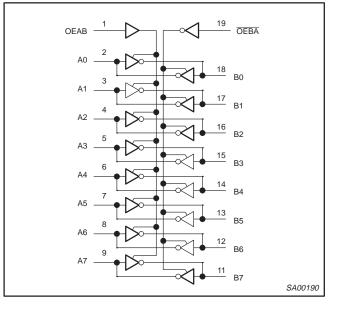
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	OEAB	Output enable input, A side to B side (active-High)
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	OEBA	Output enable input, B side to A side (active-Low)
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

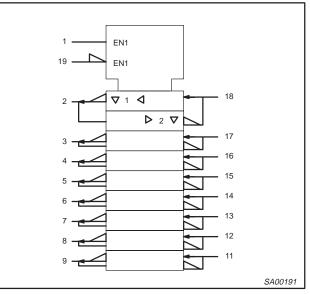
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LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INP	JTS	INPUTS/OUTPUTS
OEBA	OEAB	An Bn
L	L	Bn Inputs
Н	Н	Inputs An
н	L	Z Z
L	н	Bn Inputs or Inputs An

H = High voltage level

= Low voltage level

Z = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V _I < 0	-18	mA
VI	DC input voltage ³		-1.2 to +7.0	V
I _{ОК}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +5.5	V
I _{OUT}	DC output current	output in Low state	128	mA
T _{stg}	Storage temperature range		–65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT
		Min	Max	1
V _{CC}	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V _{CC}	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	5	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

						LIMITS			
SYMBOL	SYMBOL PARAMETER		TEST CONDITIONS		T _{amb} = +25°C			T _{amb} = −40°C to +85°C	
					Тур	Max	Min	Max	
V _{IK}	Input clamp volt	age	$V_{CC} = 4.5V; I_{IK} = -18mA$		-0.9	-1.2		-1.2	V
			V_{CC} = 4.5V; I_{OH} = –3mA; V_{I} = V_{IL} or V_{IH}	2.5	2.9		2.5		V
V _{OH}	High-level output	ut voltage	$V_{CC} = 5.0V; \ I_{OH} = -3mA; \ V_I = V_{IL} \ or \ V_{IH}$	3.0	3.4		3.0		V
			V_{CC} = 4.5V; I_{OH} = –32mA; V_{I} = V_{IL} or V_{IH}	2.0	2.4		2.0		V
V _{OL}	Low-level output	it voltage	V_{CC} = 4.5V; I_{OL} = 64mA; V_I = V_{IL} or V_{IH}		0.42	0.55		0.55	V
l _l	Input leakage	Control pins	V_{CC} = 5.5V; V_I = GND or 5.5V		±0.01	±1.0		±1.0	μΑ
	current Data pins		V_{CC} = 5.5V; V_I = GND or 5.5V		±5	±100		±100	μΑ
I _{OFF}	Power-off leakage current		V_{CC} = 0.0V; V_{O} or $V_{I}\ \leq 4.5V$		±5.0	±100		±100	μΑ
I _{PU} /I _{PD}	Power-up/down 3-State output current ³		V_{CC} = 2.1V; V_O = 0.5V; V_I = GND or V_{CC} ; V_{OE} and V_{OE} = Don't care		±5.0	±50		±50	μA
I _{IH} + I _{OZH}	3-State output H	ligh current	V_{CC} = 5.5V; V_{O} = 2.7V; V_{I} = V_{IL} or V_{IH}		5.0	50		50	μΑ
I _{IL} + I _{OZL}	3-State output L	ow current	V_{CC} = 5.5V; V_{O} = 0.5V; V_{I} = V_{IL} or V_{IH}		-5.0	-50		-50	μΑ
I _{CEX}	Output High lea	kage current	V_{CC} = 5.5V; V_{O} = 5.5V; V_{I} = GND or V_{CC}		5.0	50		50	μΑ
Ι _Ο	Output current ¹		$V_{CC} = 5.5V; V_{O} = 2.5V$	-50	-100	-180	-50	-180	mA
I _{CCH}			V_{CC} = 5.5V; Outputs High, V_I = GND or V_{CC}		50	250		250	μΑ
I _{CCL}	Quiescent supply current		V_{CC} = 5.5V; Outputs Low, V_{I} = GND or V_{CC}		24	30		30	mA
I _{CCZ}			V_{CC} = 5.5V; Outputs 3-State; V _I = GND or V _{CC}		50	250		250	μA
ΔI_{CC}	Additional supp input pin ²	ly current per	V_{CC} = 5.5V; one input at 3.4V, other inputs at V_{CC} or GND		0.05	1.5		1.5	mA

NOTES:

Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
This is the increase in supply current for each input at 3.4V.
This parameter is valid for any V_{CC} between 0V and 2.1V, with a transition time of up to 10msec. From V_{CC} = 2.1V to V_{CC} = 5V ± 10% a transition time of up to 100µsec is permitted.

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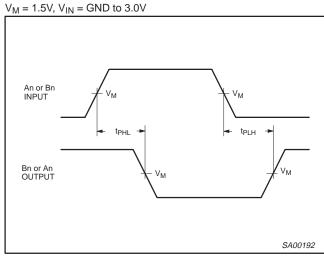
Product specification

AC CHARACTERISTICS

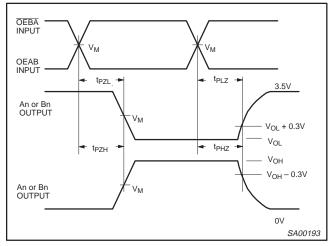
GND = 0V; t_{R} = t_{F} = 2.5ns; C_{L} = 50pF, R_{L} = 500 Ω

					LIMIT	S		
SYMBOL	PARAMETER	WAVEFORM	T _a V	amb = +25° / _{CC} = +5.0	C V	$T_{amb} = -40^{\circ}$ $V_{CC} = +5^{\circ}$	°C to +85°C .0V ±0.5V	UNIT
			Min	Тур	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	1	1.0 1.0	2.9 3.1	4.1 4.3	1.0 1.0	4.8 4.8	ns
t _{PZH} t _{PZL}	Output enable time OEBA to An	2	1.3 1.0	3.2 2.7	4.6 6.1	1.3 1.0	5.5 7.1	ns
t _{PHZ} t _{PLZ}	Output disable time OEBA to An	2	2.0 1.4	5.0 4.0	6.3 5.4	2.0 1.4	7.0 5.8	ns
t _{PZH} t _{PZL}	Output enable time OEAB to Bn	2	1.6 2.0	4.6 4.2	6.2 5.9	1.6 2.0	6.8 6.4	ns
t _{PHZ} t _{PLZ}	Output disable time OEAB to Bn	2	1.2 1.1	3.9 2.9	5.6 4.7	1.2 1.1	6.5 5.6	ns

AC WAVEFORMS



Waveform 1. Waveforms Showing the Input to Output Propagation Delays



Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times

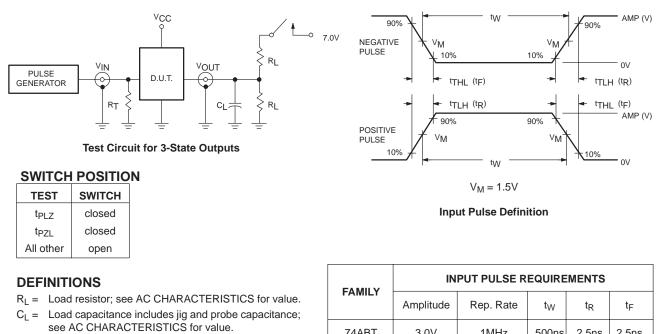
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TEST CIRCUIT AND WAVEFORMS



 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS						
	Amplitude	Rep. Rate	t _W	t _R	t _F		
74ABT	3.0V	1MHz	500ns	2.5ns	2.5ns		

SA00012

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DIP20:	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
SO20:	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1

SOT339-1

74ABT620

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm SOT360-1

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NOTES

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DEFINITIONS				
Data Sheet Identification Product Status Definition		Definition		
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.		
Preliminary Specification Preproduction Product		This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
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